



PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#6/A
D. EVANS
5-7-02

In re the Application of

Toshinari MURAI et al.

Group Art Unit: 2834

Application No.: 09/865,574

Examiner: M. Budd

Filed: May 29, 2001

Docket No.: 109605

For: PIEZOELECTRIC OXIDE SINGLE CRYSTAL WAFER

AMENDMENT UNDER 37 C.F.R. §1.111

Director of the U.S. Patent and Trademark Office
Washington, D.C. 20231

Sir:

In reply to the Office Action mailed December 28, 2001, the period for response being extended by the attached Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS:

Please add new claims 3 and 4 as follows:

--3. The piezoelectric oxide single crystal wafer according to Claim 1, wherein metal electrodes having a width of 1 μ m or less are formed on the surface of the piezoelectric oxide single crystal wafer.--

--4. The piezoelectric oxide single crystal wafer according to Claim 2, wherein metal electrodes having a width of 1 μ m or less are formed on the surface of the piezoelectric oxide single crystal wafer.--

REMARKS

Claims 1-4 are pending. By this Amendment, claims 3 and 4 are added. The addition of these claims is supported on page 5, lines 1-17 and page 9, lines 7-19 of the present

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